HER1601PT – HER1608PT

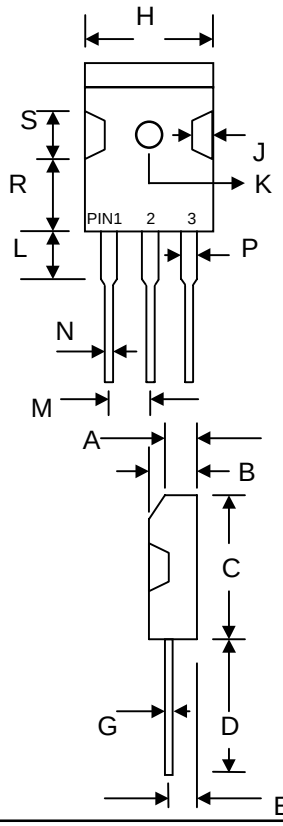
16A HIGH EFFICIENCY GLASS PASSIVATED RECTIFIER

Features

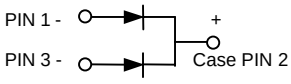
- Glass Passivated Die Construction
- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O

Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-750, Method 2026
- Polarity: See Diagram
- Weight: 5.6 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



TO-3P		
Dim	**Min**	**Max**
A	3.20	3.50
B	4.59	5.16
C	20.80	21.30
D	19.70	20.20
E	2.10	2.40
G	0.51	0.76
H	15.90	16.40
J	1.70	2.70
K	3.10 Ø	3.30 Ø
L	3.50	4.51
M	5.20	5.70
N	1.12	1.22
P	2.90	3.30
R	11.70	12.80
S	4.30 Typical	
All Dimensions in mm		



Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	HER 1601PT	HER 1602PT	HER 1603PT	HER 1604PT	HER 1605PT	HER 1606PT	HER 1607PT	HER 1608PT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	200	300	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	210	280	420	560	700	V
Average Rectified Output Current @T_C = 100°C	I_O	16								A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	200								A
Forward Voltage @I_F = 8.0A	V_{FM}	1.0				1.3	1.7			V
Peak Reverse Current @T_A = 25°C At Rated DC Blocking Voltage @T_A = 125°C	I_{RM}	10 500								µA
Reverse Recovery Time (Note 1)	t_{rr}	50					80			nS
Typical Junction Capacitance (Note 2)	C_j	85					60			pF
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150								°C

Note: 1. Measured with IF = 0.5A, IR = 1.0A, IRR = 0.25A. See figure 5.
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

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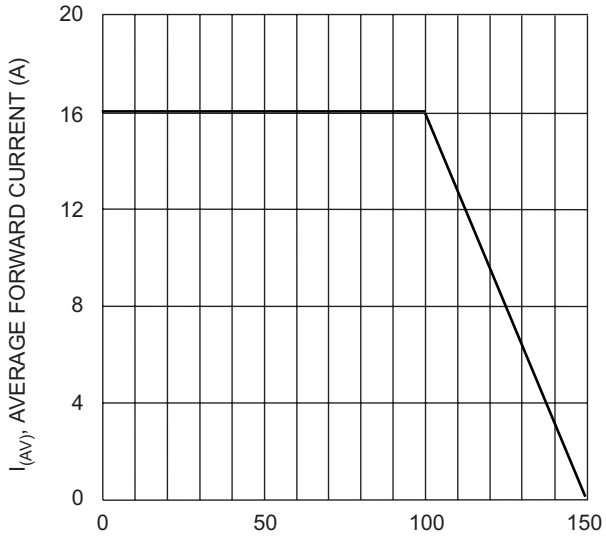


Fig. 1 Forward Current Derating Curve

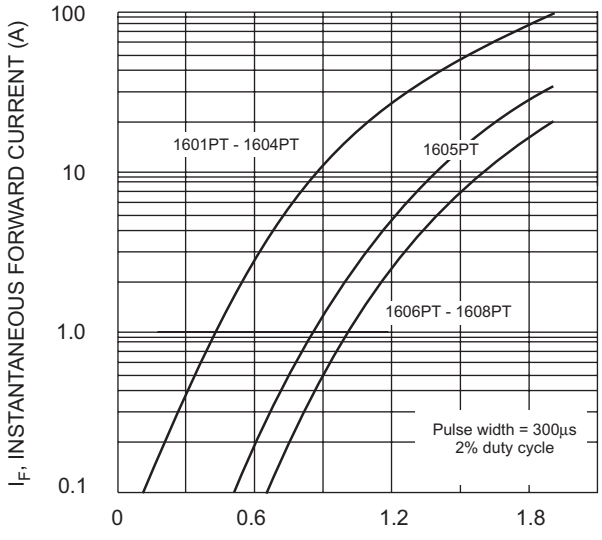


Fig. 2 Typical Forward Characteristics

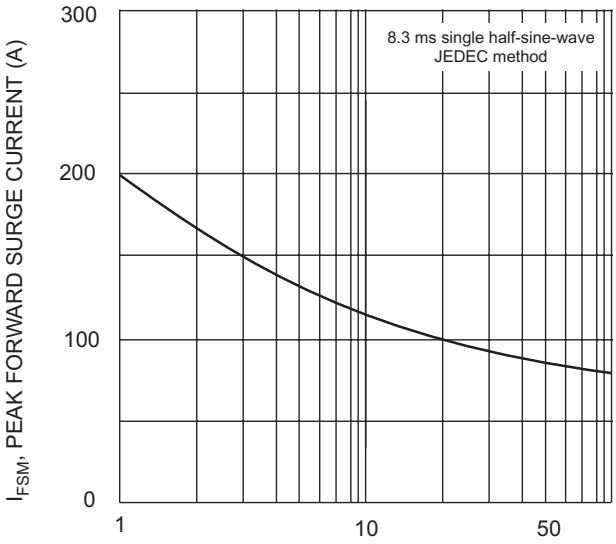


Fig. 3 Maximum Non-Repetitive Surge Current

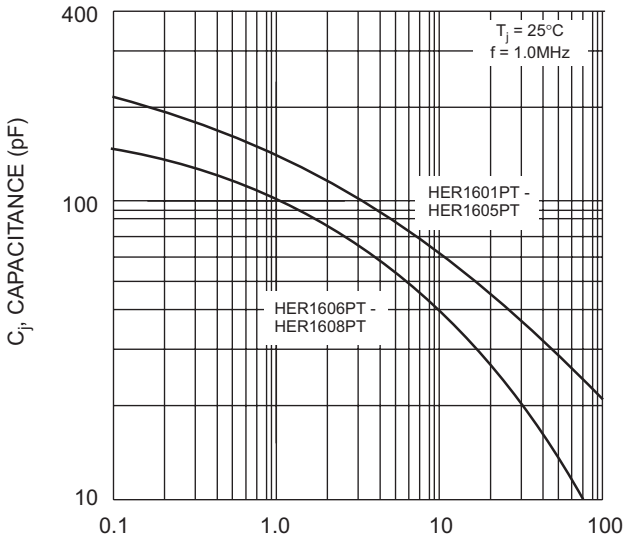
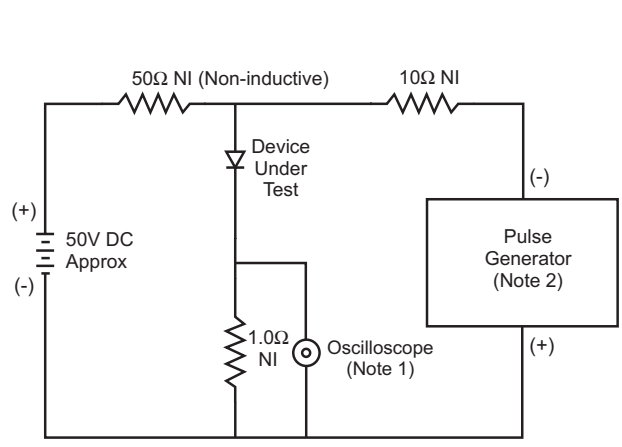


Fig. 4 Typical Junction Capacitance



Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
2. Rise Time = 10ns max. Input Impedance = 50Ω.

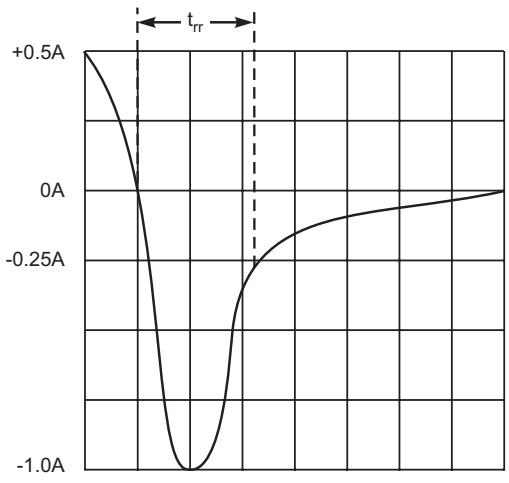


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

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ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity
HER1601PT	TO-3P	30 Units/Tube
HER1602PT	TO-3P	30 Units/Tube
HER1603PT	TO-3P	30 Units/Tube
HER1604PT	TO-3P	30 Units/Tube
HER1605PT	TO-3P	30 Units/Tube
HER1606PT	TO-3P	30 Units/Tube
HER1607PT	TO-3P	30 Units/Tube
HER1608PT	TO-3P	30 Units/Tube

Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.

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WARNING: DO NOT USE IN LIFE SUPPORT EQUIPMENT. WTE power semiconductor products are not authorized for use as critical components in life support devices or systems without the express written approval.

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